

# BCR5CM-12RA

600V - 5A - Triac

Medium Power Use

R07DS1149EJ0100

Rev.1.00

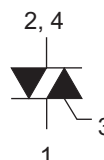
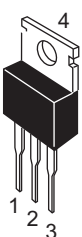
Jan 23, 2014

## Features

- $I_{T(RMS)}$  : 5 A
- $V_{DRM}$  : 600 V
- $I_{FGT I}$ ,  $I_{RGT I}$ ,  $I_{RGT III}$  : 15 mA (10 mA)<sup>Note6</sup>
- Non-Insulated Type
- Planar Passivation Type

## Outline

RENESAS Package code: PRSS0004AG-A  
(Package name: TO-220AB)



1.  $T_1$  Terminal
2.  $T_2$  Terminal
3. Gate Terminal
4.  $T_2$  Terminal

## Applications

Electric rice cooker, electric pot, and controller for other heater

## Maximum Ratings

| Parameter                                              | Symbol    | Voltage class | Unit |
|--------------------------------------------------------|-----------|---------------|------|
|                                                        |           | 12            |      |
| Repetitive peak off-state voltage <sup>Note1</sup>     | $V_{DRM}$ | 600           | V    |
| Non-repetitive peak off-state voltage <sup>Note1</sup> | $V_{DSM}$ | 720           | V    |

| Parameter                      | Symbol       | Ratings      | Unit                 | Conditions                                                                                         |
|--------------------------------|--------------|--------------|----------------------|----------------------------------------------------------------------------------------------------|
| RMS on-state current           | $I_{T(RMS)}$ | 5            | A                    | Commercial frequency, sine full wave 360° conduction, $T_c = 103^{\circ}\text{C}$ <sup>Note3</sup> |
| Surge on-state current         | $I_{TSM}$    | 50           | A                    | 60Hz sinewave 1 full cycle, peak value, non-repetitive                                             |
| $I^2t$ for fusing              | $I^2t$       | 10.4         | $\text{A}^2\text{s}$ | Value corresponding to 1 cycle of half wave 60Hz, surge on-state current                           |
| Peak gate power dissipation    | $P_{GM}$     | 3            | W                    |                                                                                                    |
| Average gate power dissipation | $P_{G(AV)}$  | 0.3          | W                    |                                                                                                    |
| Peak gate voltage              | $V_{GM}$     | 10           | V                    |                                                                                                    |
| Peak gate current              | $I_{GM}$     | 2            | A                    |                                                                                                    |
| Junction temperature           | $T_j$        | - 40 to +125 | $^{\circ}\text{C}$   |                                                                                                    |
| Storage temperature            | $T_{stg}$    | - 40 to +125 | $^{\circ}\text{C}$   |                                                                                                    |
| Mass                           | —            | 2.1          | g                    | Typical value                                                                                      |

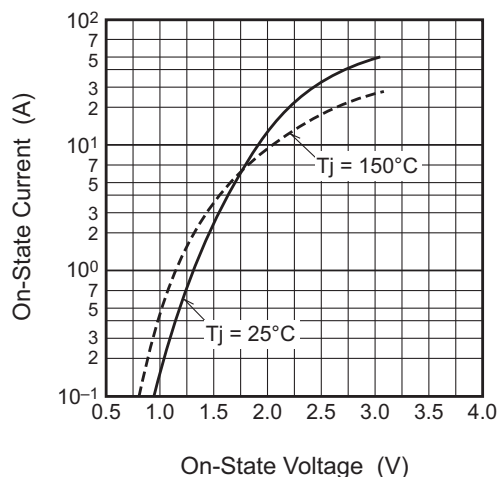
## Electrical Characteristics

| Parameter                             |     | Symbol               | Min. | Typ. | Max.                | Unit               | Test conditions                                                                            |
|---------------------------------------|-----|----------------------|------|------|---------------------|--------------------|--------------------------------------------------------------------------------------------|
| Repetitive peak off-state current     |     | $I_{\text{DRM}}$     | —    | —    | 2.0                 | mA                 | $T_j = 125^\circ\text{C}$ , $V_{\text{DRM}}$ applied                                       |
| On-state voltage                      |     | $V_{\text{TM}}$      | —    | —    | 1.8                 | V                  | $T_c = 25^\circ\text{C}$ , $I_{\text{TM}} = 7\text{ A}$ ,<br>Instantaneous measurement     |
| Gate trigger voltage <sup>Note2</sup> | I   | $V_{\text{FGT I}}$   | —    | —    | 1.5                 | V                  | $T_j = 25^\circ\text{C}$ , $V_D = 6\text{ V}$ , $R_L = 6\ \Omega$ ,<br>$R_G = 330\ \Omega$ |
|                                       | II  | $V_{\text{RGT I}}$   | —    | —    | 1.5                 | V                  |                                                                                            |
|                                       | III | $V_{\text{RGT III}}$ | —    | —    | 1.5                 | V                  |                                                                                            |
| Gate trigger current <sup>Note2</sup> | I   | $I_{\text{FGT I}}$   | —    | —    | 15 <sup>Note5</sup> | mA                 | $T_j = 25^\circ\text{C}$ , $V_D = 6\text{ V}$ , $R_L = 6\ \Omega$ ,<br>$R_G = 330\ \Omega$ |
|                                       | II  | $I_{\text{RGT I}}$   | —    | —    | 15 <sup>Note5</sup> | mA                 |                                                                                            |
|                                       | III | $I_{\text{RGT III}}$ | —    | —    | 15 <sup>Note5</sup> | mA                 |                                                                                            |
| Gate non-trigger voltage              |     | $V_{\text{GD}}$      | 0.2  | —    | —                   | V                  | $T_j = 125^\circ\text{C}$<br>$V_D = 1/2\ V_{\text{DRM}}$                                   |
| Thermal resistance                    |     | $R_{\text{th(j-c)}}$ | —    | —    | 3.0                 | $^\circ\text{C/W}$ | Junction to case <sup>Note3 Note4</sup>                                                    |

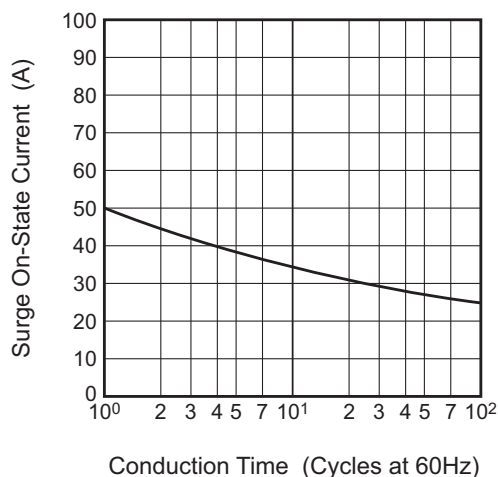
- Notes: 1. Gate open.  
2. Measurement using the gate trigger characteristics measurement circuit.  
3. Case temperature is measured at the  $T_2$  tab 1.5 mm away from the molded case.  
4. The contact thermal resistance  $R_{\text{th(c-f)}}$  in case of greasing is  $1.0^\circ\text{C/W}$ .  
5. High sensitivity ( $I_{\text{GT}} \leq 10\text{ mA}$ ) is also available. ( $I_{\text{GT}}$  item: 1)

## Performance Curves

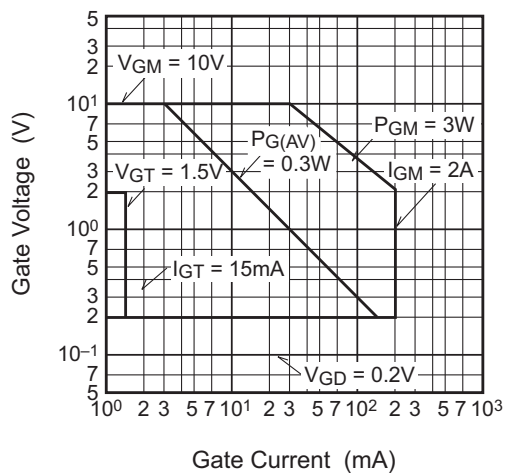
Maximum On-State Characteristics



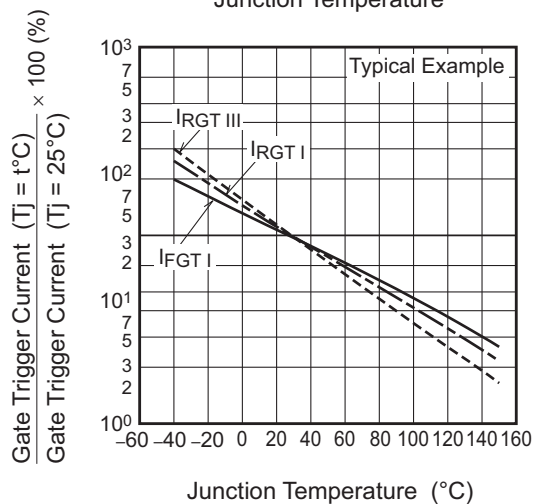
Rated Surge On-State Current



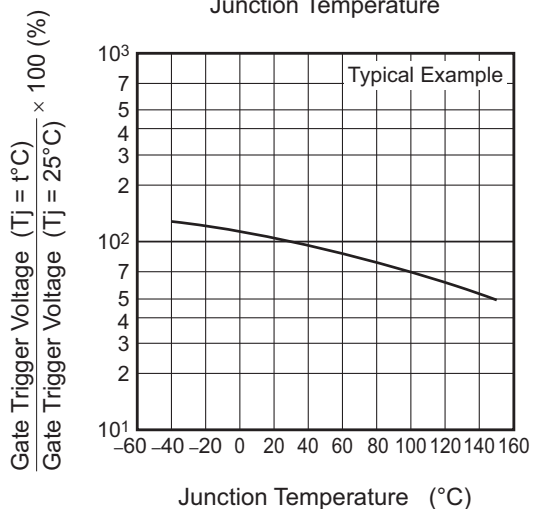
Gate Characteristics (I, II and III)



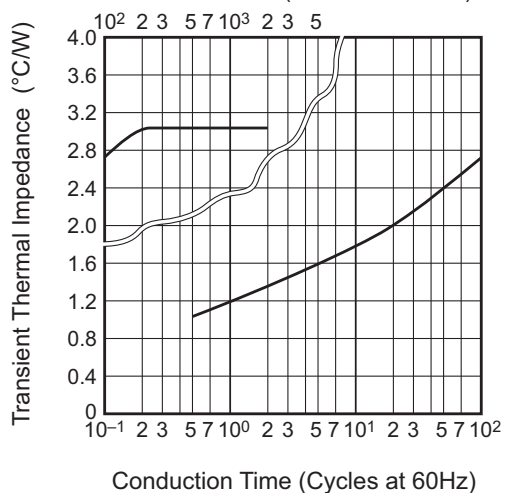
Gate Trigger Current vs. Junction Temperature



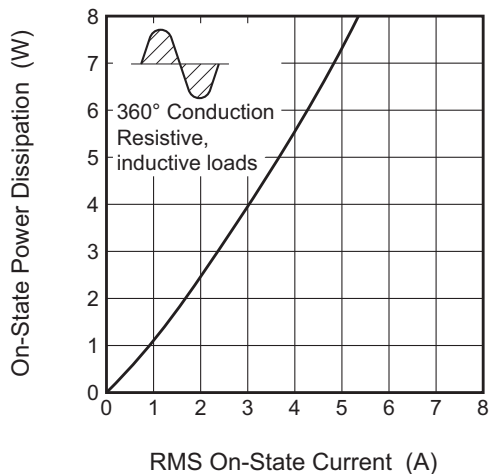
Gate Trigger Voltage vs. Junction Temperature



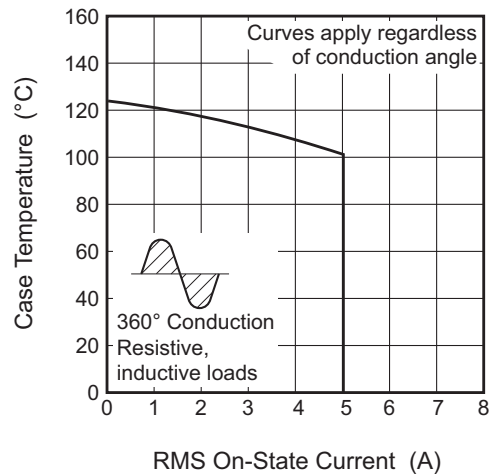
Maximum Transient Thermal Impedance Characteristics (Junction to case)



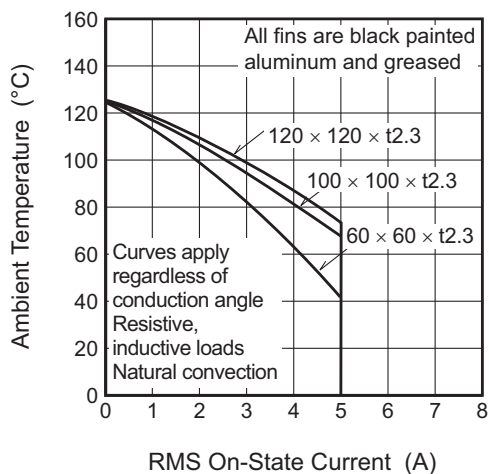
Maximum On-State Power Dissipation



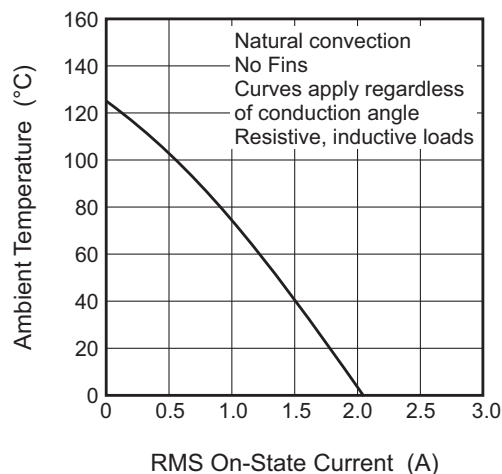
Allowable Case Temperature vs. RMS On-State Current



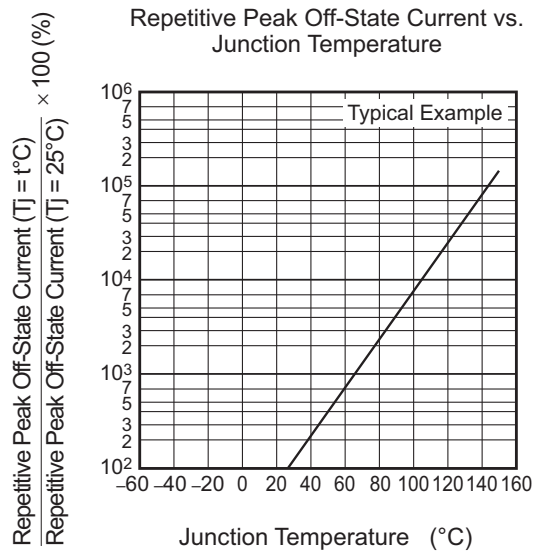
Allowable Ambient Temperature vs. RMS On-State Current



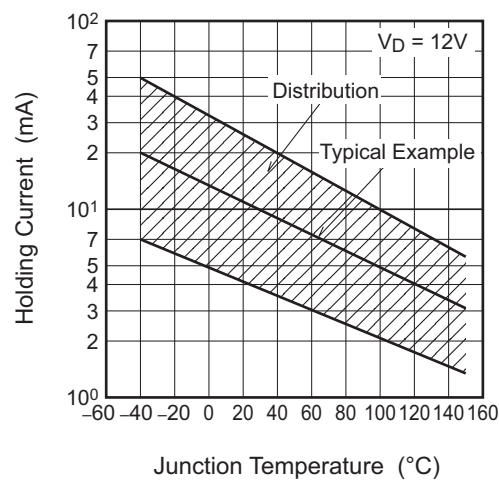
Allowable Ambient Temperature vs. RMS On-State Current

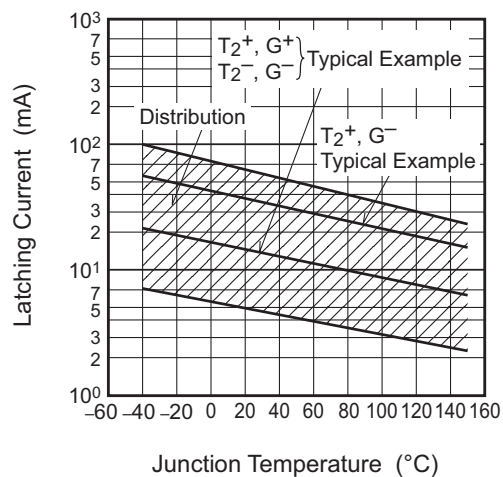
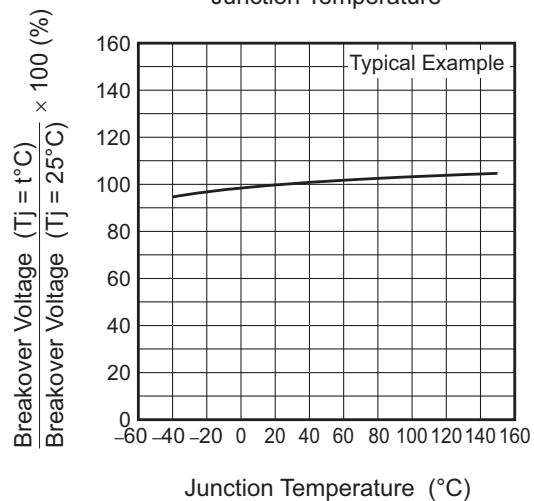
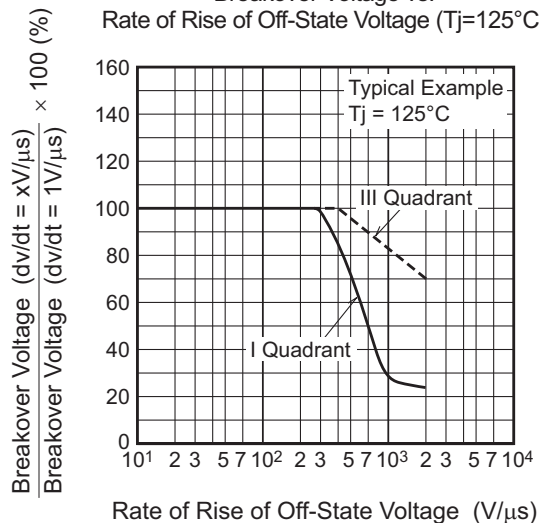
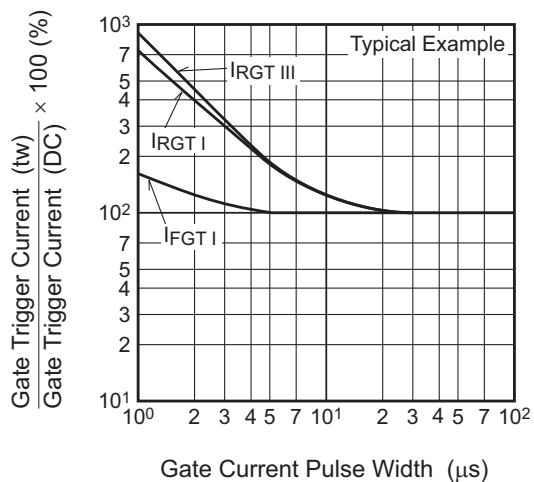


Repetitive Peak Off-State Current vs. Junction Temperature

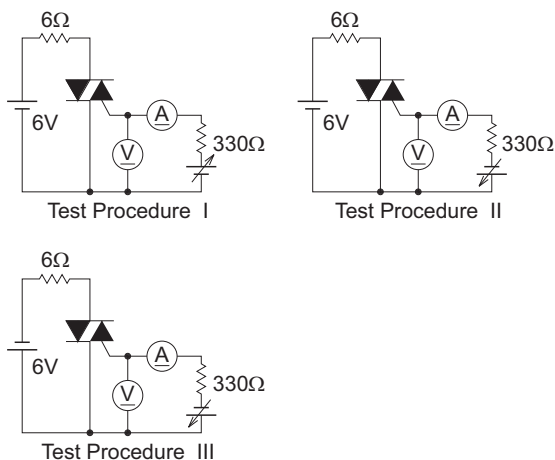


Holding Current vs. Junction Temperature

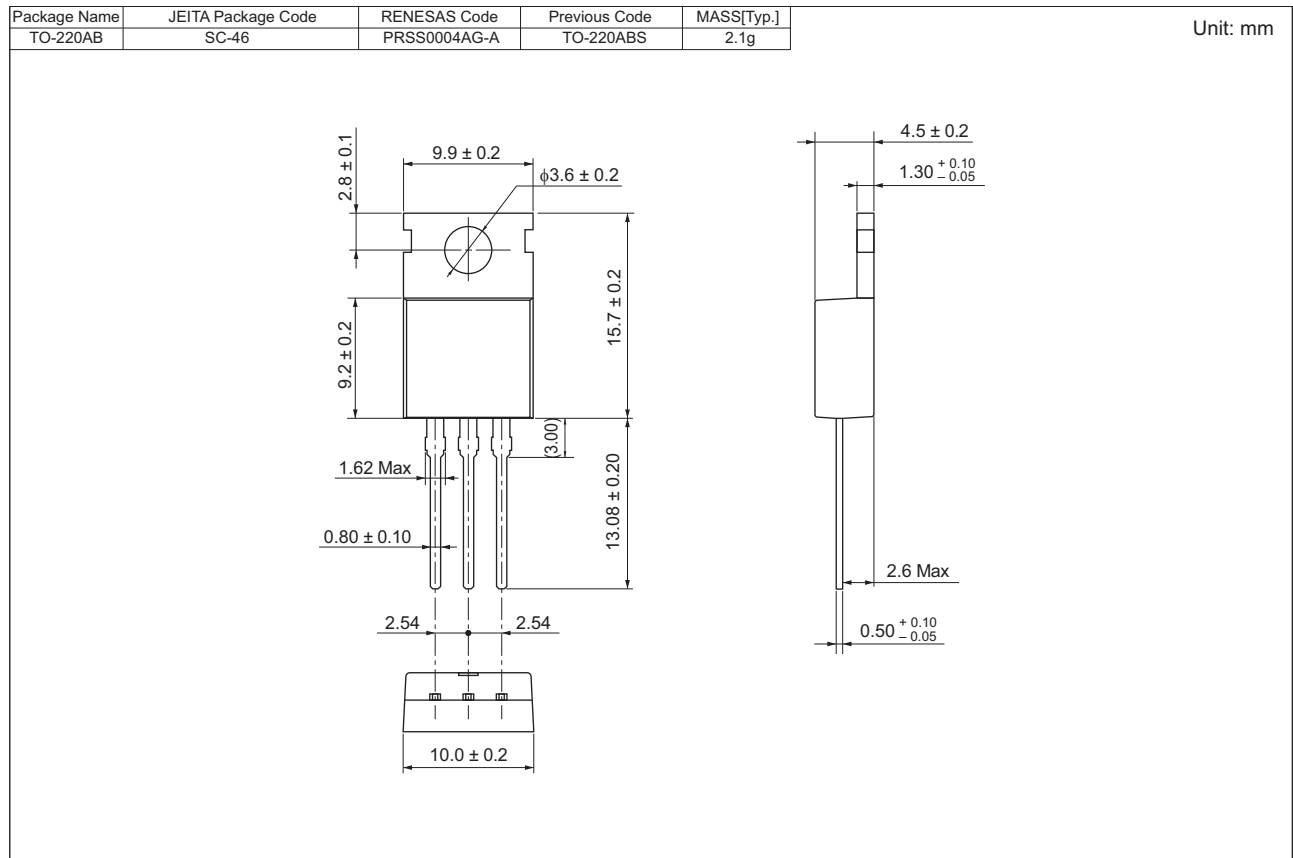


Latching Current vs.  
Junction TemperatureBreakover Voltage vs.  
Junction TemperatureBreakover Voltage vs.  
Rate of Rise of Off-State Voltage (T<sub>j</sub>=125°C)Gate Trigger Current vs.  
Gate Current Pulse Width

Gate Trigger Characteristics Test Circuits



## Package Dimensions



## Ordering Information

| Orderable Part Number | Packing | Quantity | Remark        |
|-----------------------|---------|----------|---------------|
| BCR5CM-12RA#BB0       | Tube    | 50 pcs.  | Straight type |

Note: Please confirm the specification about the shipping in detail.

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